

2N4014
SILICON
NPN TRANSISTOR



TO-18 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N4014 is a silicon NPN transistor designed for general purpose switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CB0}	80	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	I_C	1.0	A
Peak Collector Current	I_{CM}	2.0	A
Power Dissipation	P_D	0.5	W
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D	1.4	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$
Thermal Resistance	θ_{JA}	350	$^\circ\text{C/W}$
Thermal Resistance	θ_{JC}	125	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=60\text{V}$		1.7	μA
I_{CBO}	$V_{CB}=60\text{V}, T_A=100^\circ\text{C}$		120	μA
I_{CES}	$V_{CE}=80\text{V}$		10	μA
BV_{CBO}	$I_C=10\mu\text{A}$	80		V
BV_{CES}	$I_C=10\mu\text{A}$	80		V
BV_{CEO}	$I_C=10\text{mA}$	40		V
BV_{EBO}	$I_E=10\mu\text{A}$	6.0		V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		0.25	V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		0.26	V
$V_{CE(SAT)}$	$I_C=300\text{mA}, I_B=30\text{mA}$		0.40	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		0.52	V
$V_{CE(SAT)}$	$I_C=800\text{mA}, I_B=80\text{mA}$		0.80	V
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		0.95	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$		0.76	V
$V_{BE(SAT)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		0.86	V
$V_{BE(SAT)}$	$I_C=300\text{mA}, I_B=30\text{mA}$		1.1	V
$V_{BE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$	0.80	1.1	V
$V_{BE(SAT)}$	$I_C=800\text{mA}, I_B=80\text{mA}$		1.5	V
$V_{BE(SAT)}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		1.7	V

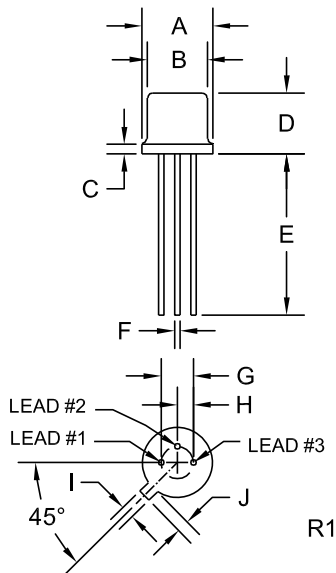
2N4014
SILICON
NPN TRANSISTOR



ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
h_{FE}	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	30		
h_{FE}	$V_{CE}=1.0\text{V}, I_C=100\text{mA}$	60	150	
h_{FE}	$V_{CE}=1.0\text{V}, I_C=100\text{mA}, T_A=-55^\circ\text{C}$	30		
h_{FE}	$V_{CE}=1.0\text{V}, I_C=300\text{mA}$	40		
h_{FE}	$V_{CE}=1.0\text{V}, I_C=500\text{mA}$	35		
h_{FE}	$V_{CE}=1.0\text{V}, I_C=500\text{mA}, T_A=-55^\circ\text{C}$	20		
h_{FE}	$V_{CE}=2.0\text{V}, I_C=800\text{mA}$	20		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$	25		
f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=100\text{MHz}$	300		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		10	pF
C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$		55	pF
t_d	$V_{CC}=30\text{V}, I_C=500\text{mA}, I_{B1}=50\text{mA}$		10	ns
t_r	$V_{CC}=30\text{V}, I_C=500\text{mA}, I_{B1}=50\text{mA}$		30	ns
t_{on}	$V_{CC}=30\text{V}, I_C=500\text{mA}, I_{B1}=50\text{mA}$		35	ns
t_s	$V_{CC}=30\text{V}, I_C=500\text{mA}, I_{B1}=I_{B2}=50\text{mA}$		50	ns
t_f	$V_{CC}=30\text{V}, I_C=500\text{mA}, I_{B1}=I_{B2}=50\text{mA}$		25	ns
t_{off}	$V_{CC}=30\text{V}, I_C=500\text{mA}, I_{B1}=I_{B2}=50\text{mA}$		60	ns

TO-18 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.209	0.230	5.31	5.84
B (DIA)	0.178	0.195	4.52	4.95
C	-	0.030	-	0.76
D	0.170	0.210	4.32	5.33
E	0.500	-	12.70	-
F (DIA)	0.016	0.019	0.41	0.48
G (DIA)	0.100		2.54	
H	0.050		1.27	
I	0.036	0.046	0.91	1.17
J	0.028	0.048	0.71	1.22

TO-18 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

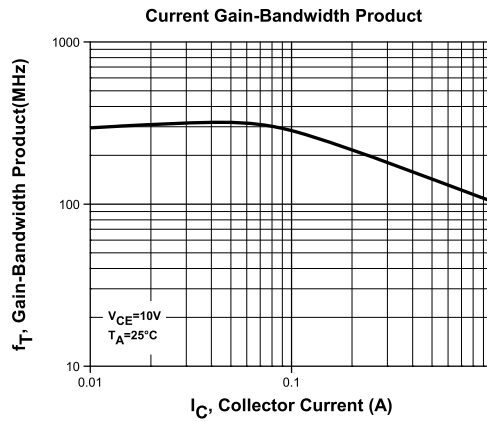
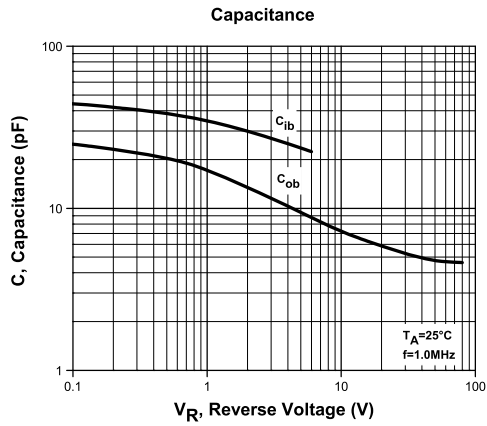
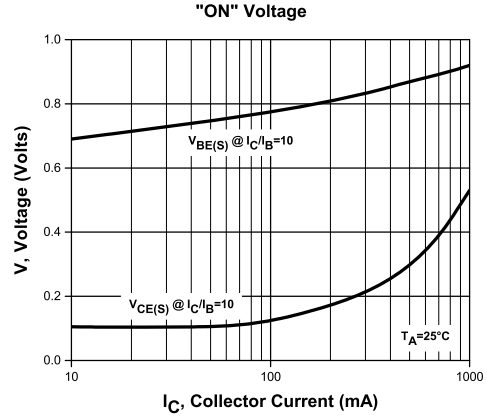
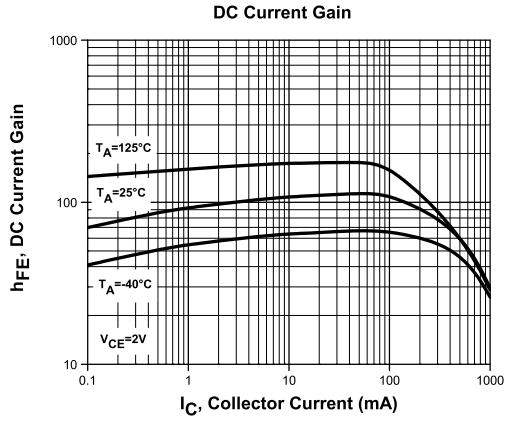
MARKING: FULL PART NUMBER

R0 (3-October 2016)

2N4014
SILICON
NPN TRANSISTOR



TYPICAL ELECTRICAL CHARACTERISTICS

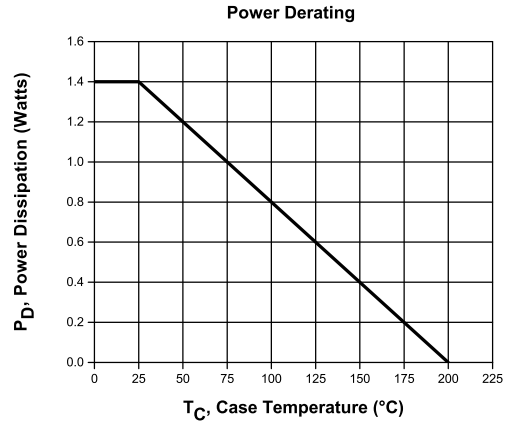
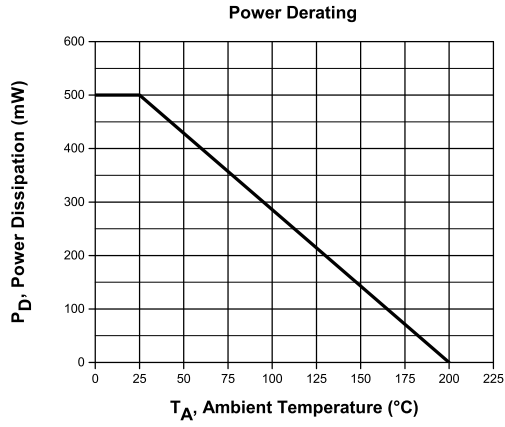


R0 (3-October 2016)

2N4014
SILICON
NPN TRANSISTOR



TYPICAL ELECTRICAL CHARACTERISTICS



R0 (3-October 2016)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.
145 Adams Avenue
Hauppauge, NY 11788 USA
Main Tel: (631) 435-1110
Main Fax: (631) 435-1824
Support Team Fax: (631) 435-3388
www.centalsemi.com

Worldwide Field Representatives:
www.centalsemi.com/wwreps

Worldwide Distributors:
www.centalsemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: www.centalsemi.com/terms